

APPLICATION DATA SHEET

APPLICATION INFORMATION

Application Type:: REGULAR
Subject Matter:: UTILITY
CD-ROM or CD-R?:: NONE
Title:: PROCESSING METHOD OF
SEMICONDUCTOR SUBSTRATE
Attorney Docket Number:: 244702US2
Total Drawing Sheets:: 10

INVENTOR INFORMATION

Applicant Authority Type:: INVENTOR
Primary Citizenship Country:: Japan
Status:: FULL CAPACITY
Given Name:: Takeshi
Family Name:: YOSHIDA
City of Residence:: Tokyo
Country of Residence:: Japan
Street of Mailing Address:: c/o Renesas Technology Corp., 4-1,
Marunouchi 2-chome, Chiyoda-ku,
City of Mailing Address:: Tokyo
Country of Mailing Address:: Japan

Applicant Authority Type:: INVENTOR
Primary Citizenship Country:: Japan
Status:: FULL CAPACITY
Given Name:: Tohru
Family Name:: KOYAMA
City of Residence:: Tokyo
Country of Residence:: Japan
Street of Mailing Address:: c/o Renesas Technology Corp., 4-1,
Marunouchi 2-chome, Chiyoda-ku,
City of Mailing Address:: Tokyo
Country of Mailing Address:: Japan

Applicant Authority Type:: INVENTOR
 Primary Citizenship Country:: Japan
 Status:: FULL CAPACITY
 Given Name:: Yoji
 Family Name:: MASHIKO
 City of Residence:: Tokyo
 Country of Residence:: Japan
 Street of Mailing Address:: c/o Renesas Technology Corp., 4-1,
 Marunouchi 2-chome, Chiyoda-ku,
 City of Mailing Address:: Tokyo
 Country of Mailing Address:: Japan

CORRESPONDENCE INFORMATION

Correspondence Customer Number:: 22850

REPRESENTATIVE INFORMATION

Representative Customer Number:: 22850

FOREIGN PRIORITY INFORMATION

Application Number:	Country::	Filing Date::	Priority Claimed::
2003-105272	Japan	04/09/03	YES

ASSIGNMENT INFORMATION

Assignee Name:: Renesas Technology Corp.
 Street of Mailing Address:: 4-1, Marunouchi 2-chome,
 Chiyoda-ku,
 City of Mailing Address:: Tokyo
 Country of Mailing Address:: Japan